300 mA, Low Dropout Voltage Regulator

The MC33275 series are micropower low dropout voltage regulators available in a wide variety of output voltages as well as packages, SOT-223, SOP-8, DPAK, and DFN 4x4 surface mount packages. These devices feature a very low quiescent current and are capable of supplying output currents up to 300 mA. Internal current and thermal limiting protection are provided by the presence of a short circuit at the output and an internal thermal shutdown circuit.

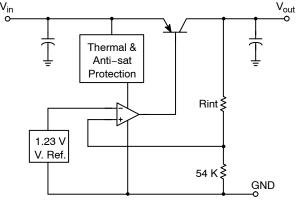
Due to the low input-to-output voltage differential and bias current specifications, these devices are ideally suited for battery powered computer, consumer, and industrial equipment where an extension of useful battery life is desirable.

Features

- Low Input–to–Output Voltage Differential of 25 mV at $I_O = 10$ mA, and 260 mV at $I_O = 300$ mA
- Extremely Tight Line and Load Regulation
- Stable with Output Capacitance of only 0.33 μF for 2.5 V Output Voltage
- Internal Current and Thermal Limiting
- NCV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable
- These are Pb-Free Devices

Applications

- Battery Powered Consumer Products
- Hand-Held Instruments
- Camcorders and Cameras



This device contains 41 active transistors

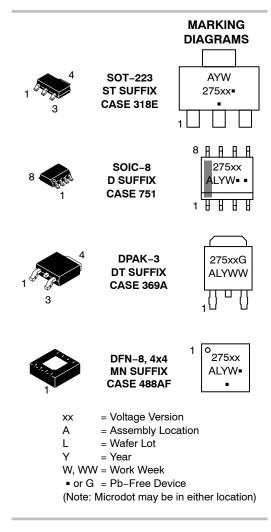




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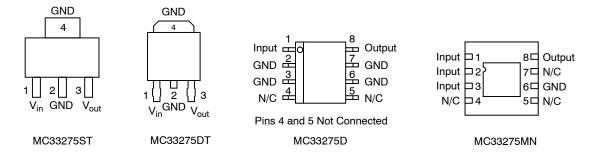
LOW DROPOUT MICROPOWER VOLTAGE REGULATOR



ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 10 of this data sheet.

PIN CONNECTIONS



MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Input Voltage	V _{CC}	13	Vdc
Power Dissipation and Thermal Characteristics $T_A = 25^{\circ}C$			
Maximum Power Dissipation Case 751 (SOIC-8) D Suffix	PD	Internally Limited	W
Thermal Resistance, Junction-to-Ambient Thermal Resistance, Junction-to-Case Case 318E (SOT-223) ST Suffix	$\begin{array}{c} R_{\theta JA} \\ R_{\theta JC} \end{array}$	160 25	°C/W °C/W
Thermal Resistance, Junction-to-Air Thermal Resistance, Junction-to-Case Case 369A (DPAK-3) DT Suffix	$R_{ heta JA} \ R_{ heta JC}$	245 15	°C/W °C/W
Thermal Resistance, Junction-to-Air Thermal Resistance, Junction-to-Case Case 488AF (DFN-8, 4x4) MN Suffix	${\sf R}_{ heta {\sf JA}} \ {\sf R}_{ heta {\sf JC}}$	92 6.0	°C/W °C/W
Thermal Resistance, Junction-to-Air (with 1.0 oz PCB cu area) Thermal Resistance, Junction-to-Air (with 1.8 oz PCB cu area) Thermal Resistance, Junction-to-Case	R _{θJA} R _{θJA} psi–JC*	183 93 9.0	°C/W °C/W °C/W
Output Current	Ι _Ο	300	mA
Maximum Junction Temperature	TJ	150	°C
Operating Ambient Temperature Range	T _A	– 40 to +125	°C
Storage Temperature Range	T _{stg}	– 65 to +150	°C
Electrostatic Discharge Sensitivity (ESD) Human Body Model (HBM) Machine Model (MM)	ESD	4000 400	V

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

*"C" ("case") is defined as the solder-attach interface between the center of the exposed pad on the bottom of the package, and the board to which it is attached.

	Characteristic	Symbol	Min	Тур	Max	Unit
Output Voltage 2.5 V Suffix 3.0 V Suffix 3.3 V Suffix 5.0 V Suffix	$I_{O} = 0 \text{ mA to } 250 \text{ mA}$ $T_{A} = 25^{\circ}\text{C}, V_{in} = [V_{O} + 1] \text{ V}$	Vo	2.475 2.970 3.267 4.950	2.50 3.00 3.30 5.00	2.525 3.030 3.333 5.05	Vdc
2.5 V Suffix 3.0 V Suffix 3.3 V Suffix 5.0 V Suffix	$V_{in} = [V_O + 1] V, 0 < I_O < 100 mA$ 2% Tolerance from $T_J = -40$ to +125°C		2.450 2.940 3.234 4.900	- - - -	2.550 3.060 3.366 5.100	
Line Regulation	$ V_{in} = [V_O + 1] V \text{ to } 12 V, I_O = 250 \text{ mA}, $	Reg _{line}	-	2.0	10	mV
Load Regulation	$V_{in} = [V_O + 1] V$, $I_O = 0$ mA to 250 mA, All Suffixes $T_A = 25^{\circ}C$	Reg _{load}	-	5.0	25	mV
$\begin{array}{l} Dropout \mbox{ Voltage } \\ I_O = 10 \mbox{ mA } \\ I_O = 100 \mbox{ mA } \\ I_O = 250 \mbox{ mA } \\ I_O = 300 \mbox{ mA } \end{array}$	$T_J = -40^{\circ}C$ to +125°C	V _{in} – V _O	- - - -	25 115 220 260	100 200 400 500	mV
Ripple Rejection ((120 Hz) $V_{in(peak-peak)} = [V_0 + 1.5] V \text{ to } [V_0 + 5.5] V$	-	65	75	-	dB
$\begin{array}{l} \text{Output Noise Volt} \\ \text{C}_{L} = 1.0 \ \mu\text{F} \\ \text{C}_{L} = 200 \ \mu\text{F} \end{array}$	age I _O = 50 mA (10 Hz to 100 kHz)	V _n		160 46		μVrms

ELECTRICAL CHARACTERISTICS (C_L = 1.0μ F, T_A = 25° C, for min/max values T_J = -40° C to $+125^{\circ}$ C, Note 1)

CURRENT PARAMETERS

$\label{eq:Quiescent Current ON Mode} \qquad \qquad V_{in} = [V_{O} + 1] \; V, \; I_{O} = 0 \; mA$	I _{QOn}	-	125	200	μA
	I _{QSAT}		1100 1500 1500 1500	1500 2000 2000 2000	μΑ
$\label{eq:Vin} Current \ Limit \qquad \qquad V_{in} = [V_O + 1] \ V, \ V_O \ Shorted$	I _{LIMIT}	-	450	_	mA

_

_

150

_

°C

THERMAL SHUTDOWN

Thermal Shutdown

1. Low duty pulse techniques are used during test to maintain junction temperature as close to ambient as possible. 2. Quiescent Current is measured where the PNP pass transistor is in saturation. $V_{in} = [V_0 - 0.5]$ V guarantees this condition.

DEFINITIONS

Load Regulation – The change in output voltage for a change in load current at constant chip temperature.

Dropout Voltage – The input/output differential at which the regulator output no longer maintains regulation against further reductions in input voltage. Measured when the output drops 100 mV below its nominal value (which is measured at 1.0 V differential), dropout voltage is affected by junction temperature, load current and minimum input supply requirements.

Output Noise Voltage – The RMS AC voltage at the output with a constant load and no input ripple, measured over a specified frequency range.

Maximum Power Dissipation – The maximum total dissipation for which the regulator will operate within specifications.

Quiescent Current – Current which is used to operate the regulator chip and is not delivered to the load.

Line Regulation – The change in output voltage for a change in the input voltage. The measurement is made under conditions of low dissipation or by using pulse techniques such that the average chip temperature is not significantly affected.

Maximum Package Power Dissipation – The maximum package power dissipation is the power dissipation level at which the junction temperature reaches its maximum value i.e. 150° C. The junction temperature is rising while the difference between the input power (V_{CC} X I_{CC}) and the output power (V_{out} X I_{out}) is increasing.

Depending on ambient temperature, it is possible to calculate the maximum power dissipation and so the maximum current as following:

$$\mathsf{Pd} = \frac{\mathsf{T}_{\mathsf{J}} - \mathsf{T}_{\mathsf{A}}}{\mathsf{R}_{\mathsf{H},\mathsf{IA}}}$$

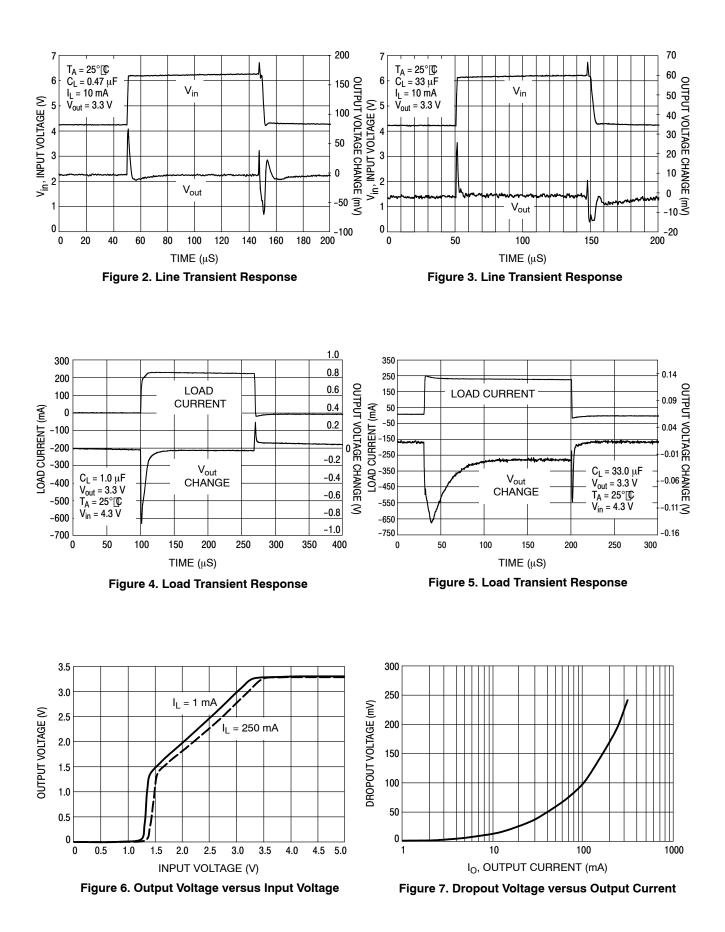
The maximum operating junction temperature T_J is specified at 150°C, if $T_A = 25$ °C, then P_D can be found. By neglecting the quiescent current, the maximum power dissipation can be expressed as:

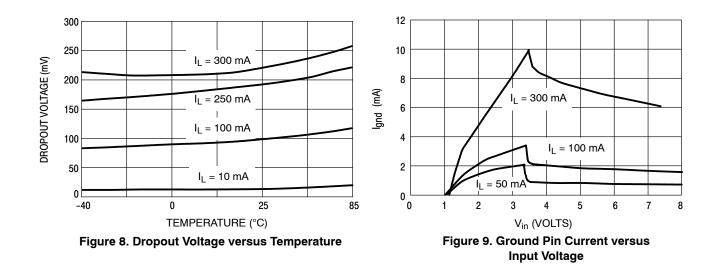
$$I_{out} = \frac{P_D}{V_{CC} - V_{out}}$$

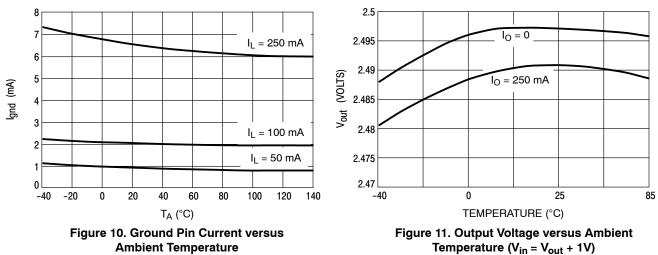
The thermal resistance of the whole circuit can be evaluated by deliberately activating the thermal shutdown of the circuit (by increasing the output current or raising the input voltage for example).

Then you can calculate the power dissipation by subtracting the output power from the input power. All variables are then well known: power dissipation, thermal shutdown temperature and ambient temperature.

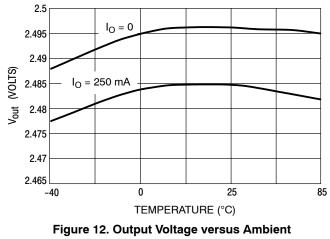
$$\mathsf{R}_{\theta \mathsf{J}\mathsf{A}} = \frac{\mathsf{T}_{\mathsf{J}} - \mathsf{T}_{\mathsf{A}}}{\mathsf{P}_{\mathsf{D}}}$$



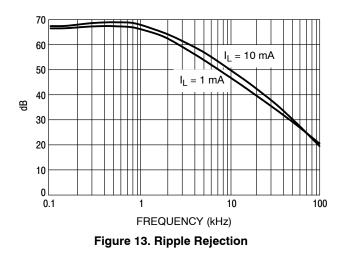


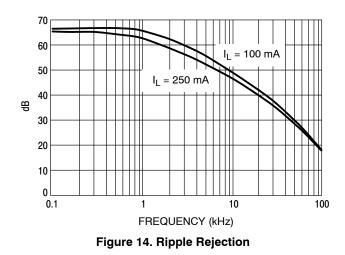


Ambient Temperature



Temperature (V_{in} = 12 V)





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APPLICATIONS INFORMATION

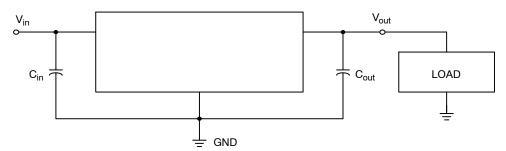


Figure 15. Typical Application Circuit

The MC33275 regulators are designed with internal current limiting and thermal shutdown making them user-friendly. Figure 15 is a typical application circuit. The output capability of the regulator is in excess of 300 mA, with a typical dropout voltage of less than 260 mV. Internal protective features include current and thermal limiting.

EXTERNAL CAPACITORS

These regulators require only a 0.33 μ F (or greater) capacitance between the output and ground for stability for 1.8 V, 2.5 V, 3.0 V, and 3.3 V output voltage options. Output voltage options of 5.0 V require only 0.22 µF for stability. The output capacitor must be mounted as close as possible to the MC33275. If the output capacitor must be mounted further than two centimeters away, then a larger value of output capacitor may be required for stability. A value of 0.68 µF or larger is recommended. Most type of aluminum, tantalum, or multilayer ceramic will perform adequately. Solid tantalums or appropriate multilayer ceramic capacitors are recommended for operation below 25°C. An input bypass capacitor is recommended to improve transient response or if the regulator is connected to the supply input filter with long wire lengths, more than 4 inches. This will reduce the circuit's sensitivity to the input line impedance at high frequencies. A 0.33 µF or larger tantalum, mylar, ceramic, or other capacitor having low internal impedance at high frequencies should be chosen. The bypass capacitor should be mounted with shortest possible lead or track length directly across the regulator's input terminals. Figure 16 shows the ESR that allows the LDO to remain stable for various load currents.

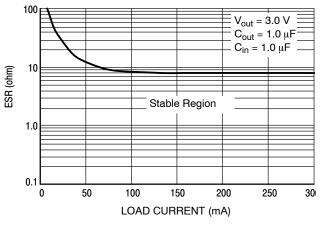


Figure 16. ESR for Vout = 3.0V

Applications should be tested over all operating conditions to insure stability.

THERMAL PROTECTION

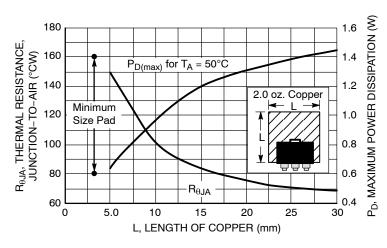
Internal thermal limiting circuitry is provided to protect the integrated circuit in the event that the maximum junction temperature is exceeded. When activated, typically at 150°C, the output is disabled. There is no hysteresis built into the thermal protection. As a result the output will appear to be oscillating during thermal limit. The output will turn off until the temperature drops below the 150°C then the output turns on again. The process will repeat if the junction increases above the threshold. This will continue until the existing conditions allow the junction to operate below the temperature threshold.

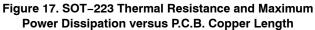
Thermal limit is not a substitute for proper heatsinking.

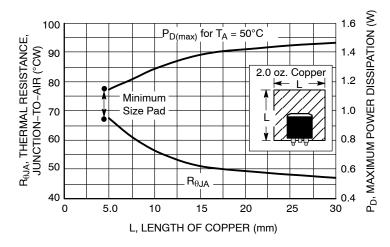
The internal current limit will typically limit current to 450 mA. If during current limit the junction exceeds 150°C, the thermal protection will protect the device also. **Current limit is not a substitute for proper heatsinking.**

OUTPUT NOISE

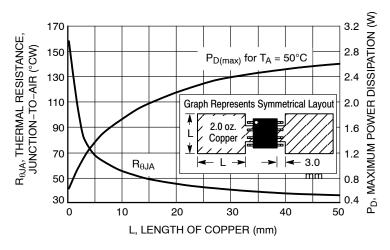
In many applications it is desirable to reduce the noise present at the output. Reducing the regulator bandwidth by increasing the size of the output capacitor will reduce the noise.













ORDERING INFORMATION

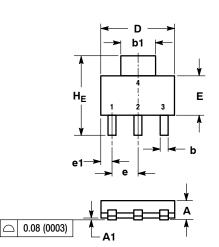
Device	V _O Typ (V)	Operating Temperature Range, Tolerance	Case	Package	Marking	Shipping [†]
MC33275D-2.5G			751	SOIC-8 (Pb-Free)	27525	98 Units/Rail
MC33275D-2.5R2G			751	SOIC-8 (Pb-Free)	27525	2500/Tape & Reel
MC33275DT-2.5G	2.5 V		369A	DPAK (Pb-Free)	27525G	75 Units/Rail
MC33275DT-2.5RKG	(Fixed Voltage)		369A	DPAK (Pb-Free)	27525G	2500/Tape & Reel
MC33275MN-2.5R2G	-	1% Tolerance at T _A = 25°C	488AF	DFN8 (Pb-Free)	27525	3000/Tape & Reel
MC33275ST-2.5T3G			318E	SOT-223 (Pb-Free)	27525	4000/Tape & Reel
MC33275D-3.0G			751	SOIC-8 (Pb-Free)	27530	98 Units/Rail
MC33275D-3.0R2G	-	2% Tolerance at T, from –40°C to +125°C	751	SOIC-8 (Pb-Free)	27530	2500/Tape & Reel
MC33275DT-3.0G	3.0 V		369A	DPAK (Pb-Free)	27530G	75 Units/Rail
MC33275DT-3.0RKG	(Fixed Voltage)		369A	DPAK (Pb-Free)	27530G	2500/Tape & Reel
MC33275MN-3.0R2G	-		488AF	DFN8 (Pb–Free)	27530	3000/Tape & Reel
MC33275ST-3.0T3G			318E	SOT-223 (Pb-Free)	27530	4000/Tape & Ree
MC33275D-3.3G			751	SOIC-8 (Pb-Free)	27533	98 Units/Rail
MC33275D-3.3R2G		1% Tolerance at T _A = 25°C	751	SOIC-8 (Pb-Free)	27533	2500/Tape & Reel
MC33275DT-3.3G	-		369A	DPAK (Pb-Free)	27533G	75 Units/Rail
MC33275DT-3.3RKG	3.3 V (Fixed Voltage)		369A	DPAK (Pb-Free)	27533G	2500/Tape & Reel
MC33275ST-3.3T3G	-	2% Tolerance at T, from -40°C to +125°C	318E	SOT-223 (Pb-Free)	27533	4000/Tape & Reel
NCV33275ST3.3T3G*	-	1% Tolerance at T _A = 25°C	318E	SOT-223 (Pb-Free)	27533	4000/Tape & Reel
MC33275MN-3.3R2G			488AF	DFN-8 (Pb-Free)	27330	3000/Tape & Reel
MC33275D-5.0G		1% Tolerance at T _A = 25°C	751	SOIC-8 (Pb-Free)	27550	98 Units/Rail
MC33275D-5.0R2G			751	SOIC-8 (Pb-Free)	27550	2500/Tape & Reel
MC33275DT-5.0G	5.0 V		369A	DPAK (Pb-Free)	27550G	75 Units/Rail
MC33275DT-5.0RKG	(Fixed Voltage)	2% Tolerance at T.I from -40°C to +125°C	369A	DPAK (Pb-Free)	27550G	2500/Tape & Ree
MC33275MN-5.0R2G		1% Tolerance at $T_A = 25^{\circ}C$	488AF	DFN-8 (Pb-Free)	27550	3000/Tape & Ree
MC33275ST-5.0T3G			318E	SOT-223 (Pb-Free)	27550	4000/Tape & Ree
NCV33275ST-5.0T3G*			318E	SOT-223 (Pb-Free)	27550	4000/Tape & Ree

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

*NCV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable

PACKAGE DIMENSIONS

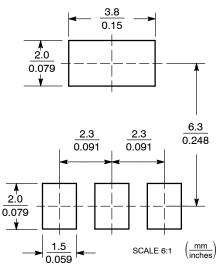
SOT-223 (TO-261) ST SUFFIX CASE 318E-04 **ISSUE N**



NOTES: 1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994. 2. CONTROLLING DIMENSION: INCH.

	MILLIMETERS			INCHES		
DIM	MIN	NOM	MAX	MIN	NOM	MAX
Α	1.50	1.63	1.75	0.060	0.064	0.068
A1	0.02	0.06	0.10	0.001	0.002	0.004
b	0.60	0.75	0.89	0.024	0.030	0.035
b1	2.90	3.06	3.20	0.115	0.121	0.126
С	0.24	0.29	0.35	0.009	0.012	0.014
D	6.30	6.50	6.70	0.249	0.256	0.263
E	3.30	3.50	3.70	0.130	0.138	0.145
е	2.20	2.30	2.40	0.087	0.091	0.094
e1	0.85	0.94	1.05	0.033	0.037	0.041
L	0.20			0.008		
L1	1.50	1.75	2.00	0.060	0.069	0.078
HE	6.70	7.00	7.30	0.264	0.276	0.287
θ	0°	-	10°	0°	-	10°

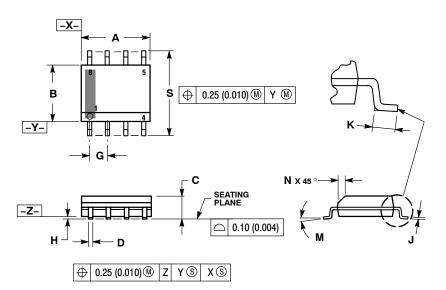
SOLDERING FOOTPRINT*



*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

PACKAGE DIMENSIONS

SOIC-8 NB D SUFFIX CASE 751-07 **ISSUE AK**



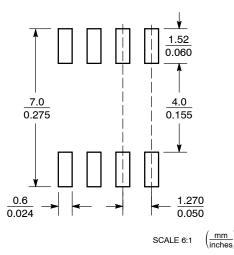
NOTES:

- NOTES:
 DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 CONTROLLING DIMENSION: MILLIMETER.
 DIMENSION A AND B DO NOT INCLUDE MOLD PROTRUSION.
 MAXIMUM MOLD PROTRUSION 0.15 (0.006)
- MAXIMUM MOLD PROTRUSION 0.15 (0.006) PER SIDE.
 DIMENSION D DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE DAMBAR PROTRUSION SHALL BE 0.127 (0.005) TOTAL IN EXCESS OF THE D DIMENSION AT MAXIMUM MATERIAL CONDITION.
 751-01 THRU 751-06 ARE OBSOLETE. NEW STANDARD IS 751-07

STANDARD IS 751-07.						
	MILLIN	IETERS	INC	HES		
DIM	MIN	MAX	MIN	MAX		
Α	4.80	5.00	0.189	0.197		
В	3.80	4.00	0.150	0.157		
С	1.35	1.75	0.053	0.069		
D	0.33	0.51	0.013	0.020		
6	1.07	P BCC	0.05	0 BSC		

u	1.21	030	0.05	0.000
Н	0.10	0.25	0.004	0.010
J	0.19	0.25	0.007	0.010
к	0.40	1.27	0.016	0.050
м	0 °	8 °	0 °	8 °
Ν	0.25	0.50	0.010	0.020
s	5.80	6.20	0.228	0.244

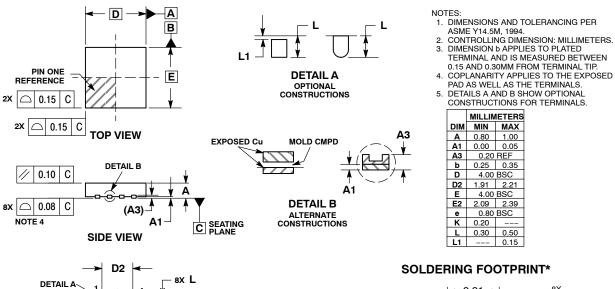
SOLDERING FOOTPRINT*

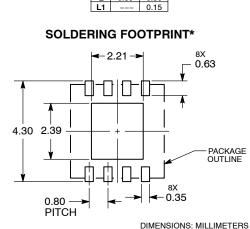


*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

PACKAGE DIMENSIONS

8 PIN DFN, 4x4 **MN SUFFIX** CASE 488AF ISSUE C





MILLIMETERS

1.91 2.21

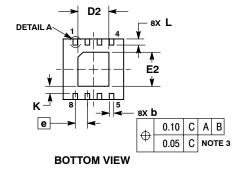
4.00 BSC

2.09 2.39

0.80 BSC

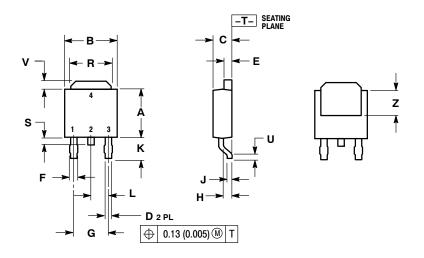
0.30 0.50

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.



PACKAGE DIMENSIONS

DPAK-3 DT SUFFIX CASE 369A-13 **ISSUE AB**



NOTES

1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH.

	INC	HES	MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.235	0.250	5.97	6.35
В	0.250	0.265	6.35	6.73
С	0.086	0.094	2.19	2.38
D	0.027	0.035	0.69	0.88
E	0.033	0.040	0.84	1.01
F	0.037	0.047	0.94	1.19
G	0.180 BSC		4.58	BSC
Н	0.034	0.040	0.87	1.01
J	0.018	0.023	0.46	0.58
K	0.102	0.114	2.60	2.89
L	0.090	BSC	2.29	BSC
R	0.175	0.215	4.45	5.46
S	0.020	0.050	0.51	1.27
U	0.020		0.51	
۷	0.030	0.050	0.77	1.27
Z	0.138		3.51	

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